

SILICON NPN POWER DARLINGTON TRANSISTOR

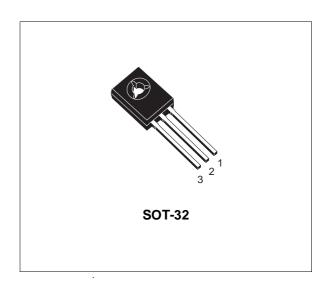
- STMicroelectronics PREFERRED SALESTYPE
- NPN DARLINGTON

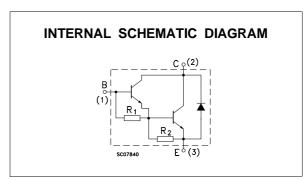
APPLICATIONS

■ GENERAL PURPOSE SWITCHING

DESCRIPTION

The MJE802 is a silicon Epitaxial-Base NPN transistor in monolithic Darlington configuration, mounted in Jedec SOT-32 plastic package. It is intended for use in medium power linear and switching applications.





ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|------------------|--|------------|------|
| V _{CBO} | Collector-Base Voltage (I _E = 0) | 80 | V |
| V_{CEO} | Collector-Emitter Voltage (I _B = 0) | 80 | V |
| V_{EBO} | Base-Emitter Voltage (I _C = 0) | 5 | V |
| Ic | Collector Current | 4 | Α |
| Ι _Β | Base Current | 0.1 | А |
| P_{tot} | Total Power Dissipation at T _{case} ≤ 25 °C | 40 | W |
| T_{stg} | Storage Temperature | -65 to 150 | °C |
| Tj | Max Operating Junction Temperature | 150 | °C |

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THERMAL DATA

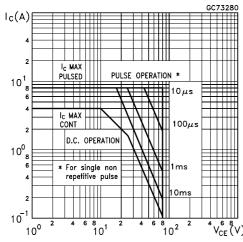
| R _{thj-amb} | Thermal Resistance Junction-ambient | Max | 3.13 | °C/W | ĺ |
|----------------------|-------------------------------------|-----|------|------|---|
|----------------------|-------------------------------------|-----|------|------|---|

ELECTRICAL CHARACTERISTICS ($T_{case} = 25$ °C unless otherwise specified)

| Symbol | Parameter | Test Conditions | | rameter Test Conditions Min. Ty | | Тур. | Тур. Мах. | |
|-------------------------|---|---|--|---------------------------------|--|------------|-----------|--|
| I _{CBO} | Collector Cut-off Current (I _E = 0) | V_{CB} = rated V_{CBO} V_{CB} = rated V_{CBO} T_{case} = 100 °C | | | | 100 500 | μA μA | |
| I _{CEO} | Collector Cut-off Current (I _B = 0) | V _{CE} = rated V _{CEO} | | | | 100 | μΑ | |
| I _{EBO} | Emitter Cut-off Current (I _C = 0) | V _{EB} = 5 V | | | | 2 | mA | |
| V _{CEO(sus)} * | Collector-Emitter Sustaining Voltage (I _B = 0) | I _C = 50 mA | | 80 | | | V | |
| V _{CE(sat)*} | Collector-Emitter Saturation Voltage | I _C = 4 A I _C = 1.5 A | $I_B = 40 \text{ mA}$ $I_B = 30 \text{ mA}$ | | | 3 2.5 | V V | |
| V _{BE} * | Base-Emitter Voltage | I _C = 4 A I _C = 1.5 A | V _{CE} = 3 V V _{CE} = 3 V | | | 3 2.5 | V V | |
| h _{FE} * | DC Current Gain | I _C = 4 A I _C = 1.5 A | V _{CE} = 3 V V _{CE} = 3 V | 100 750 | | | | |
| h _{fe} | Small Signal Current Gain | I _C = 1.5 A f = 1 MHz | V _{CE} = 3 V | 1 | | | | |

^{*} Pulsed: Pulse duration = 300µs, duty cycle ≤ 1.5%

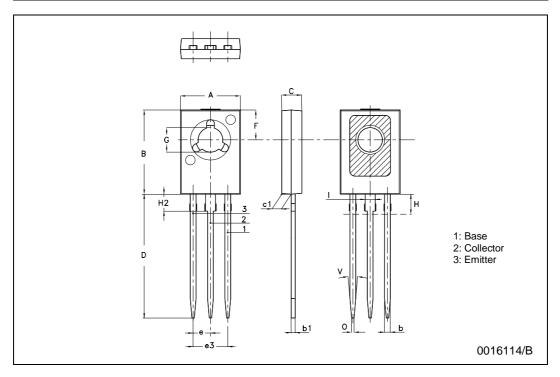
Safe Operating Area



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SOT-32 (TO-126) MECHANICAL DATA

| DIM. | | mm | | | inch | |
|------|------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| Α | 7.4 | | 7.8 | 0.291 | | 0.307 |
| В | 10.5 | | 10.8 | 0.413 | | 0.425 |
| b | 0.7 | | 0.9 | 0.028 | | 0.035 |
| b1 | 0.40 | | 0.65 | 0.015 | | 0.025 |
| С | 2.4 | | 2.7 | 0.094 | | 0.106 |
| c1 | 1.0 | | 1.3 | 0.039 | | 0.051 |
| D | 15.4 | | 16.0 | 0.606 | | 0.630 |
| е | | 2.2 | | | 0.087 | |
| e3 | | 4.4 | | | 0.173 | |
| F | | 3.8 | | | 0.150 | |
| G | 3 | | 3.2 | 0.118 | | 0.126 |
| Н | | | 2.54 | | | 0.100 |
| H2 | | 2.15 | | | 0.084 | |
| I | | 1.27 | | | 0.05 | |
| 0 | | 0.3 | | | 0.011 | _ |
| V | | 10° | | | 10° | |



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